

# CD4060B Types

## CMOS 14-Stage Ripple-Carry Binary Counter/Divider and Oscillator

### High-Voltage Types (20-Volt Rating)

■ CD4060B consists of an oscillator section and 14 ripple-carry binary counter stages. The oscillator configuration allows design of either RC or crystal oscillator circuits. A RESET input is provided which resets the counter to the all-0's state and disables the oscillator. A high level on the RESET line accomplishes the reset function. All counter stages are master-slave flip-flops. The state of the counter is advanced one step in binary order on the negative transition of  $\phi_0$  (and  $\phi_0$ ). All inputs and outputs are fully buffered. Schmitt trigger action on the input-pulse line permits unlimited input-pulse rise and fall times.

The CD4060B-series types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline package (NSR suffix), and in chip form (H suffix).

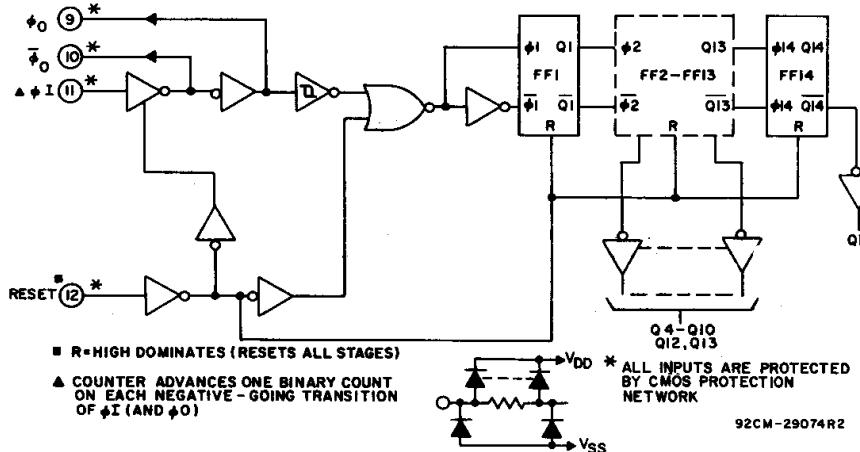


Fig. 1 – Logic diagram.

#### MAXIMUM RATINGS; Absolute Maximum Values:

##### DC SUPPLY-VOLTAGE RANGE, ( $V_{DD}$ )

Voltages referenced to  $V_{SS}$  Terminal ..... -0.5V to +20V

##### INPUT VOLTAGE RANGE, ALL INPUTS

DC INPUT CURRENT, ANY ONE INPUT ..... -0.5V to  $V_{DD}$  +0.5V

##### POWER DISSIPATION PER PACKAGE ( $P_D$ ):

For  $T_A = -55^\circ\text{C}$  to  $+100^\circ\text{C}$  ..... 500mW

For  $T_A = +100^\circ\text{C}$  to  $+125^\circ\text{C}$  ..... Derate Linearity at 12mW/ $^\circ\text{C}$  to 200mW

##### DEVICE DISSIPATION PER OUTPUT TRANSISTOR

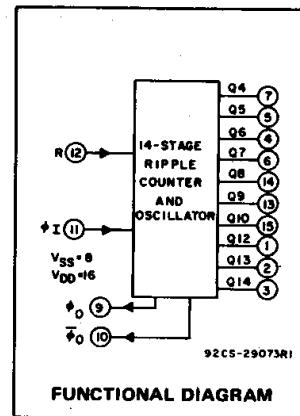
FOR  $T_A = \text{FULL PACKAGE-TEMPERATURE RANGE (All Package Types)}$  ..... 100mW

OPERATING-TEMPERATURE RANGE ( $T_A$ ) ..... -55 $^\circ\text{C}$  to +125 $^\circ\text{C}$

STORAGE TEMPERATURE RANGE ( $T_{stg}$ ) ..... -65 $^\circ\text{C}$  to +150 $^\circ\text{C}$

##### LEAD TEMPERATURE (DURING SOLDERING):

At distance  $1/16 \pm 1/32$  inch ( $1.59 \pm 0.79$ mm) from case for 10s max ..... +265 $^\circ\text{C}$



#### Features:

- 12 MHz clock rate at 15 V
- Common reset
- Fully static operation
- Buffered inputs and outputs
- Schmitt trigger input-pulse line
- 100% tested for quiescent current at 20 V
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for description of 'B' Series CMOS Devices"

#### Oscillator Features:

- All active components on chip
- RC or crystal oscillator configuration
- RC oscillator frequency of 690 kHz min. at 15 V

#### Applications

- Control counters
- Timers
- Frequency dividers
- Time-delay circuits

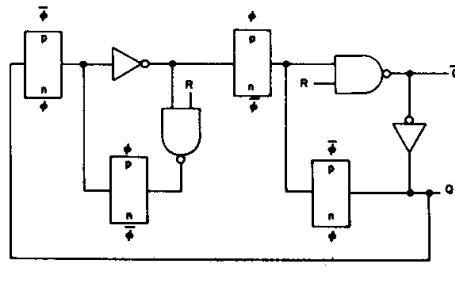


Fig. 2 – Detail of typical flip-flop stage.

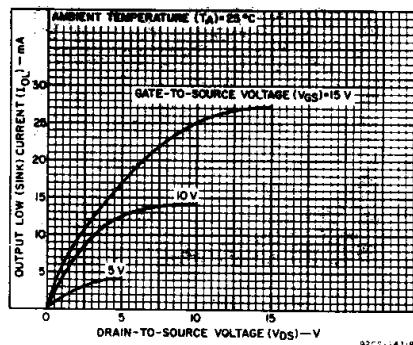


Fig. 3 – Typical n-channel output low (sink) current characteristics.

# CD4060B Types

## STATIC ELECTRICAL CHARACTERISTICS

CHARAC- TERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)						UNITS	
	$V_O$ (V)	$V_{IN}$ (V)	$V_{DD}$ (V)	-55	-40	+85	+125	+25			
								Min.	Typ.	Max.	
Quiescent Device Current, $I_{DD}$ Max.	-	0.5	5	5	5	150	150	-	0.04	5	$\mu A$
	-	0.10	10	10	10	300	300	-	0.04	10	
	-	0.15	15	20	20	600	600	-	0.04	20	
	-	0.20	20	100	100	3000	3000	-	0.08	100	
Output Low (Sink) Current*, $I_{OL}$ Min.	0.4	0.5	5	0.64	0.61	0.42	0.36	0.51	1	-	$mA$
	0.5	0.10	10	1.6	1.5	1.1	0.9	1.3	2.6	-	
	1.5	0.15	15	4.2	4	2.8	2.4	3.4	6.8	-	
Output High (Source) Current*, $I_{OH}$ Min.	4.6	0.5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	$mA$
	2.5	0.5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	
	9.5	0.10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
	13.5	0.15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	-	
Output Voltage: Low-Level, $V_{OL}$ Max.	-	0.5	5	0.05			-	0	0.05	-	$V$
	-	0.10	10	0.05			-	0	0.05	-	
	-	0.15	15	0.05			-	0	0.05	-	
Output Voltage: High-Level, $V_{OH}$ Min.	-	0.5	5	4.95			4.95	5	-	-	$V$
	-	0.10	10	9.95			9.95	10	-	-	
	-	0.15	15	14.95			14.95	15	-	-	
Input Low Voltage $V_{IL}$ Max.	0.5,4.5	-	5	1.5			-	-	1.5	-	$V$
	1.9	-	10	3			-	-	3	-	
	1.5,13.5	-	15	4			-	-	4	-	
Input High Voltage, $V_{IH}$ Min.	0.5,4.5	-	5	3.5			3.5	-	-	-	$V$
	1.9	-	10	7			7	-	-	-	
	1.5,13.5	-	15	11			11	-	-	-	
Input Current $I_{IN}$ Max.	-	0.18	18	$\pm 0.1$	$\pm 0.1$	$\pm 1$	$\pm 1$	-	$\pm 10^{-5}$	$\pm 0.1$	$\mu A$

\* Data not applicable to terminal 9 or 10.

## RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges

CHARACTERISTIC	$V_{DD}$	LIMITS		UNITS
		MIN.	MAX.	
Supply-Voltage Range (For $T_A =$ Full Package Temperature Range)	-	3	18	V
Input-Pulse Width, $t_W$ ( $f = 100$ kHz)	5	100	-	ns
	10	40	-	
	15	30	-	
Input-Pulse Rise Time and Fall Time, $t_{r\phi}, t_{f\phi}$	5	Unlimited		
	10			
	15			
Input-Pulse Frequency, $f_{pL}$ (External pulse source)	5	-	3.5	MHz
	10	-	8	
	15	-	12	
Reset Pulse Width, $t_W$	5	120	-	ns
	10	60	-	
	15	40	-	

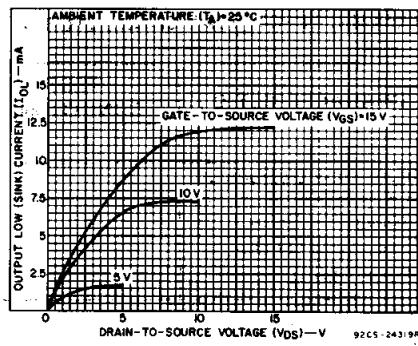


Fig. 4 – Minimum n-channel output low (sink) current characteristics.

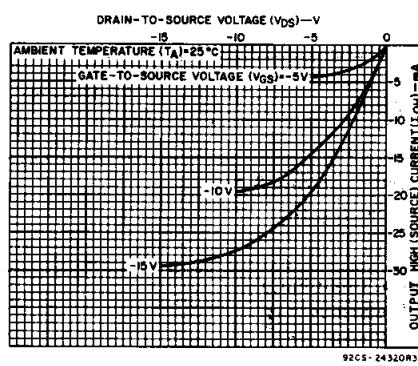


Fig. 5 – Typical p-channel output high (source) current characteristics.

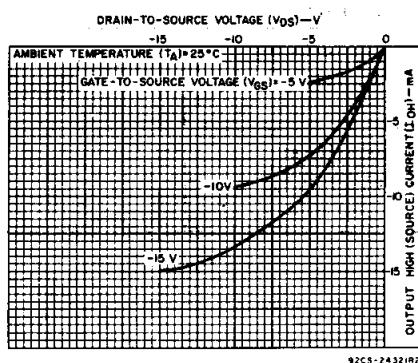


Fig. 6 – Minimum p-channel output high (source) current characteristics.

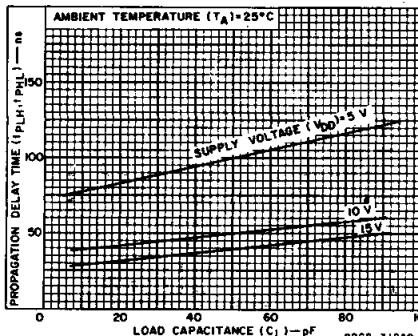


Fig. 7 – Typical propagation delay time ( $t_{PHL}$ ,  $t_{PHL'}$ ) as a function of load capacitance.

## CD4060B Types

**DYNAMIC ELECTRICAL CHARACTERISTICS** at  $T_A = 25^\circ\text{C}$ , Input  $t_r, t_f = 20 \text{ ns}$ ,  
 $C_L = 50 \text{ pF}$ ,  $R_L = 200 \text{ k}\Omega$

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		V <sub>DD</sub> (V)	MIN.	TYP.	
<b>Input-Pulse Operation</b>					
Propagation Delay Time, $\phi_I$ to Q4 Out; t <sub>PHL</sub> , t <sub>TPLH</sub>		5	—	370	740
		10	—	150	300
		15	—	100	200
Propagation Delay Time, Q <sub>n</sub> to Q <sub>n+1</sub> ; t <sub>PHL</sub> , t <sub>TPLH</sub>		5	—	100	200
		10	—	50	100
		15	—	40	80
Transition Time, t <sub>THL</sub> , t <sub>TLH</sub>		5	—	100	200
		10	—	50	100
		15	—	40	80
Min. Input-Pulse Width, t <sub>W</sub>	f = 100 kHz	5	—	50	100
		10	—	20	40
		15	—	15	30
Input-Pulse Rise & Fall Time, t <sub>rφ</sub> , t <sub>fφ</sub>		5	Unlimited		
		10	Unlimited		
		15	Unlimited		
Max. Input-Pulse Frequency, f <sub>φ</sub> (External pulse source)		5	3.5	7	—
		10	8	16	—
		15	12	24	—
Input Capacitance, C <sub>1</sub>	Any Input	—	5	7.5	pF
<b>Reset Operation</b>					
Propagation Delay Time, t <sub>PHL</sub>		5	—	180	360
		10	—	80	160
		15	—	50	100
Minimum Reset Pulse Width, t <sub>W</sub>		5	—	60	120
		10	—	30	60
		15	—	20	40

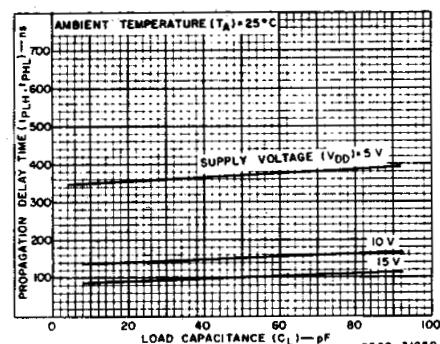


Fig. 8 – Typical propagation delay time ( $\phi_I$  to Q<sub>4</sub> Output) as a function of load capacitance.

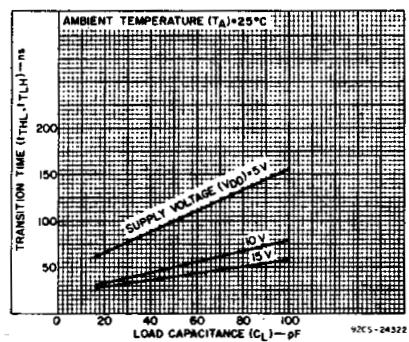


Fig. 9 – Typical transition time as a function of load capacitance.

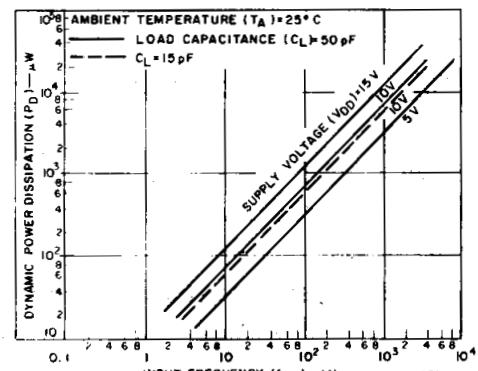


Fig. 10 – Typical dynamic power dissipation as a function of input frequency.

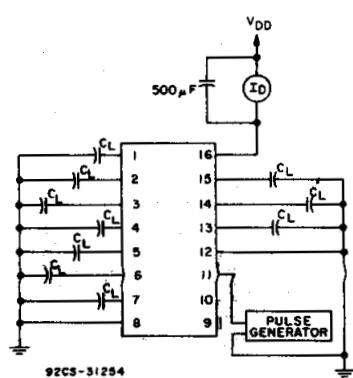


Fig. 11 – Dynamic power dissipation test circuit.

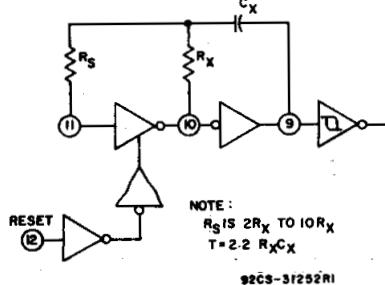


Fig. 12 – Typical RC circuit.

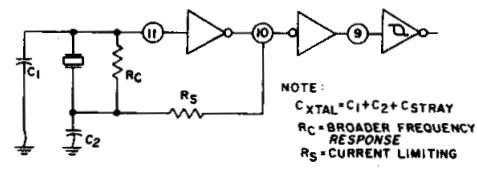


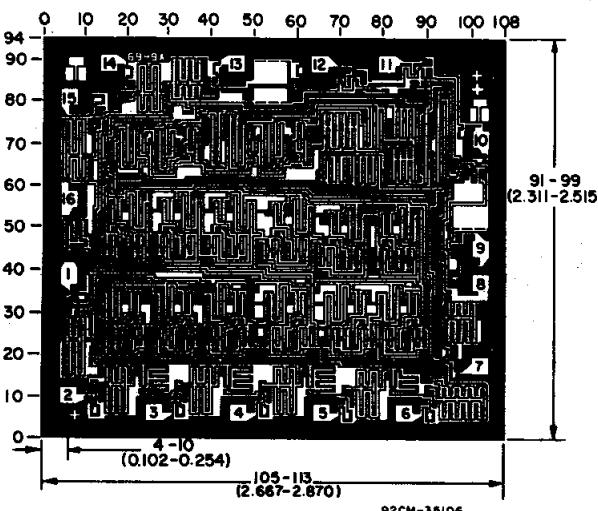
Fig. 13 – Typical crystal circuit.

## CD4060B Types

**DYNAMIC ELECTRICAL CHARACTERISTICS** at  $T_A = 25^\circ\text{C}$ , Input  $t_r, t_f = 20 \text{ ns}$ ,  
 $C_L = 50 \text{ pF}$ ,  $R_L = 200 \text{ k}\Omega$  [cont'd]

CHARACTERISTIC	TEST CONDITIONS	$V_{DD}$ (V)	LIMITS			UNITS
			Min.	Typ.	Max.	
<b>RC Operation</b>						
Variation of Frequency (Unit-to-Unit)	$C_X = 200 \text{ pF}$ , $R_S = 560 \text{ k}\Omega$ , $R_X = 50 \text{ k}\Omega$	5	—	$23 \pm 10\%$	—	kHz
		10	—	$24 \pm 10\%$	—	
		15	—	$25 \pm 10\%$	—	
Variation of Frequency with voltage change (Same Unit)	$C_X = 200 \text{ pF}$ , $R_S = 560 \text{ k}\Omega$ , $R_X = 50 \text{ k}\Omega$	5V to 10 V	—	1.5	—	
		10V to 15V	—	0.5	—	
$R_X$ max.	$C_X = 10 \mu\text{F}$ = $50 \mu\text{F}$ = $10 \mu\text{F}$	5	—	—	20	$\text{M}\Omega$
		10	—	—	20	
		15	—	—	10	
$C_X$ max.	$R_X = 500 \text{ k}\Omega$ = $300 \text{ k}\Omega$ = $300 \text{ k}\Omega$	5	—	—	1000	$\mu\text{F}$
		10	—	—	50	
		15	—	—	50	
Maximum Oscillator Frequency*	$R_X = 5 \text{ k}\Omega$ $R_S = 30 \text{ k}\Omega$ $C_X = 15 \text{ pF}$	10	530	650	810	kHz
		15	690	800	940	
Drive Current at Pin 9 (For Oscillator Design)	$I_{OL}$	$V_O = 0.4 \text{ V}$	5	0.16	0.35	
		$= 0.5 \text{ V}$	10	0.42	0.8	
		$= 1.5 \text{ V}$	15	1	2	
	$I_{OH}$	$V_O = 4.6 \text{ V}$	5	-0.16	-0.35	
		$= 9.5 \text{ V}$	10	-0.42	-0.8	
		$= 13.5 \text{ V}$	15	-1	-2	

\*RC oscillator applications are not recommended at supply voltages below 7 V for  $R_X < 50 \text{ k}\Omega$ .



Chip dimensions and pad layout for CD4060B

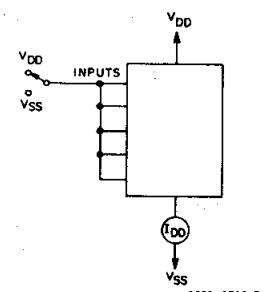


Fig. 14 – Quiescent device current.

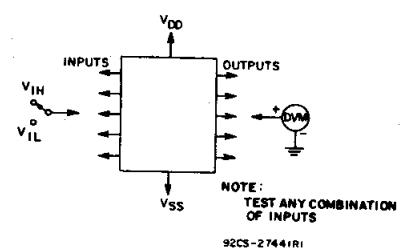


Fig. 15 – Input voltage.

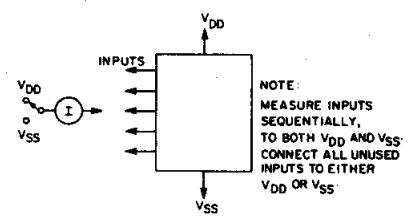
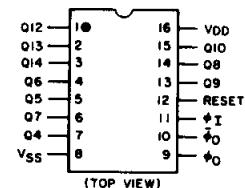


Fig. 16 – Input current.

### TERMINAL DIAGRAM



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils ( $10^{-3}$  inch).

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